

VS-E5TX1506THN3

Vishay Semiconductors

RoHS

FREE

Hyperfast Rectifier, 15 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS								
I _{F(AV)}	15 A							
V _R	600 V							
V _F at I _F at 125 °C	1.3 V							
t _{rr} (typ.)	19 ns							
T _J max.	175 °C							
Package	TO-220AC 2L							
Circuit configuration	Single							

FEATURES

- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV on-board battery chargers

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating **Terminals:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Repetitive peak reverse voltage	V _{RRM}		600	V					
Average rectified forward current	I _{F(AV)}	T _C = 129 °C, D = 0.50	15						
Repetitive peak forward current	I _{FRM}	T _C = 129 °C, D = 0.50, f = 20 kHz	30	А					
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave	185						
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C					

ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)									
PARAMETER	MIN.	TYP.	MAX.	UNITS					
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-				
Forward voltage	V _F	I _F = 15 A	-	1.6	2.1	V			
		I _F = 15 A, T _J = 125 °C	-	1.3	-				
Deviewe lealers average		$V_{R} = V_{R}$ rated	-	-	10				
Reverse leakage current	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$		-	500	μA			
Junction capacitance	CT	V _R = 200 V	-	25	-	pF			
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH			

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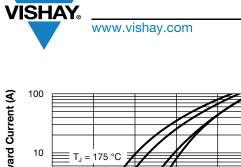
DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A,d}I_F/c$	$I_F = 1.0 \text{ A,} dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$			-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	23	-	ns			
		T _J = 125 °C		-	36	-				
Peak recovery current	1	T _J = 25 °C	I _F = 10 A dI _F /dt = 1000 A/μs V _R = 400 V	-	12	-	A			
	I _{RRM}	T _J = 125 °C		-	20	-				
D	Q _{rr}	T _J = 25 °C		-	180	-	nC			
Reverse recovery charge		T _J = 125 °C		-	472	-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	33	-	ns			
Reverse recovery time		T _J = 125 °C		-	44	-				
Poak receivery ourrent	I _{RRM}	T _J = 25 °C	l _F = 15 A dl _F /dt = 1000 A/µs	-	13	-	A nC			
Peak recovery current		T _J = 125 °C	$V_{\rm R} = 400 \text{ V}$	-	21	-				
Reverse recovery charge	0	T _J = 25 °C		-	220	-				
	Q _{rr}	T _J = 125 °C		-	578	-				

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.72	°C/W			
Woisht			-	2.0	-	g			
Weight			-	0.07	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C			
Marking device		Case style TO-220AC 2L	E5TX1506TH						

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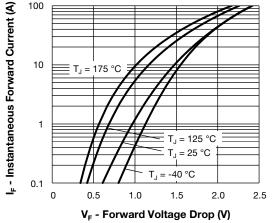


Fig. 1 - Forward Voltage Drop Characteristics, Per Leg

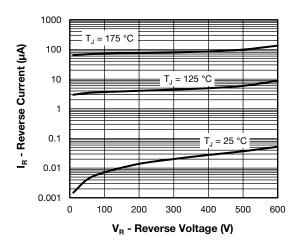


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg

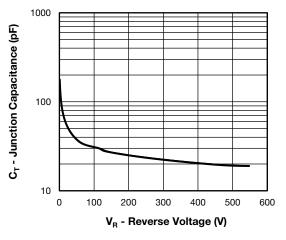


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

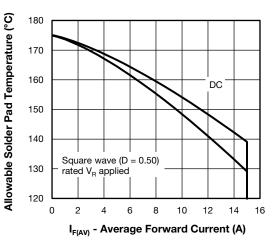


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Leg

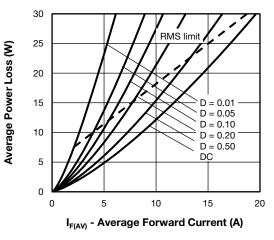
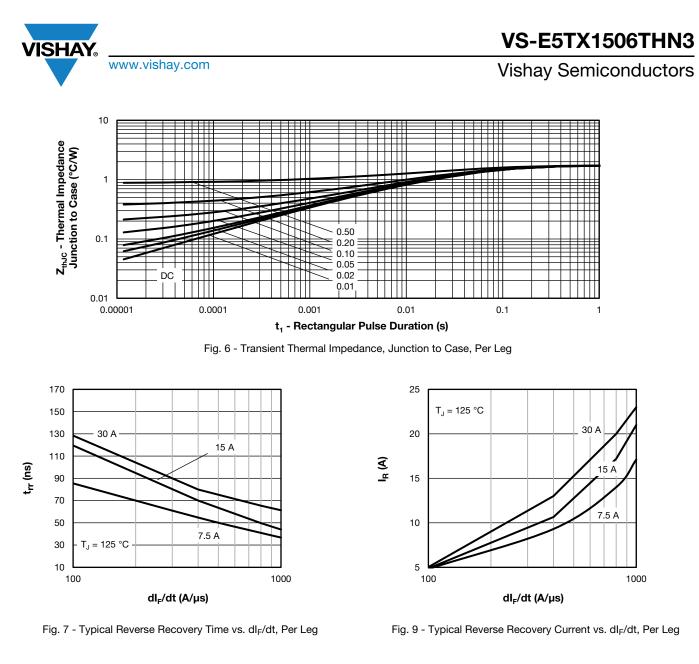


Fig. 5 - Forward Power Loss Characteristics, Per Leg

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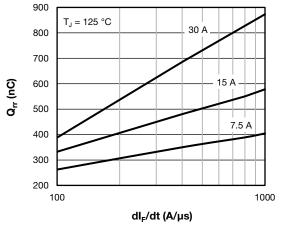


Fig. 8 - Typical Reverse Recovery Charge vs. $dI_{\mbox{\scriptsize F}}/dt,$ Per Leg

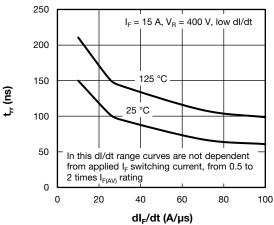


Fig. 10 - Typical Reverse Recovery Time vs. dI_F/dt , Per Leg

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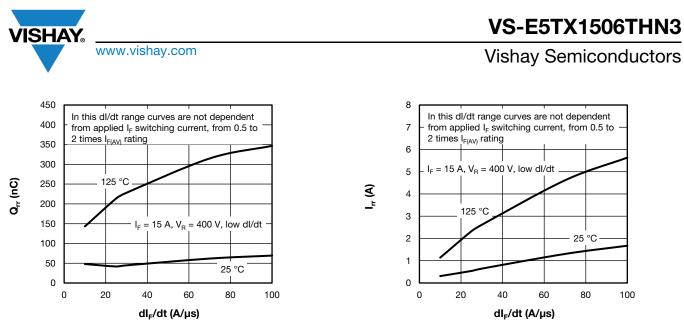


Fig. 11 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg

Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt, Per Leg

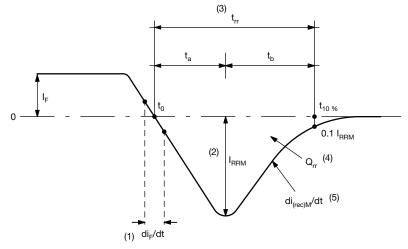


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM} (4) Q_{rr} area under curve defined by t_0 and $t_{10\%}$

$$Q_{rr} = \int_{t}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

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ORDERING INFORMATION TABLE

Device code VS-Ε 5 15 06 Т Х Т Η **N3** 8 9 (6) $\overline{7}$ (10) (2) 3 4 (5) Vishay Semiconductors product 1 2 E = single diode 3 5 = FRED generation 5 4 Package: _ T = TO-220AC 2L 5 X = hyperfast recovery 6 Current rating (15 = 15 A) 7 Voltage rating (06 = 600 V) 8 T = true pin TO-220 _ 9 H = AEC-Q101 qualified _ 10 Environmental digit: N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTIO									
VS-E5TX1506THN3	50	1000	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96069
Part marking information	www.vishay.com/doc?95391

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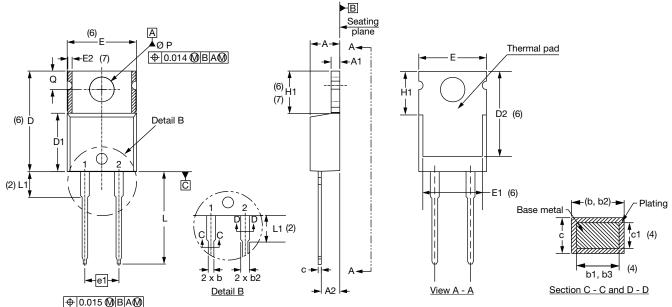


Outline Dimensions

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TO-220AC 2L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES		SYMBOL	MILLIMETERS		INCHES		NOTES	
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183			E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055			E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115			e1	4.88	5.28	0.192	0.208	
b	0.69	1.01	0.027	0.040			H1	5.84	6.86	0.230	0.270	6, 7
b1	0.38	0.97	0.015	0.038	4		L	13.52	14.02	0.532	0.552	
b2	1.20	1.73	0.047	0.068			L1	3.32	3.82	0.131	0.150	2
b3	1.14	1.73	0.045	0.068	4		ØР	3.54	3.73	0.139	0.147	
с	0.36	0.61	0.014	0.024			Q	2.60	3.00	0.102	0.118	
c1	0.36	0.56	0.014	0.022	4							
D	14.85	15.25	0.585	0.600	3							
D1	8.38	9.02	0.330	0.355								
D2	11.68	12.88	0.460	0.507	6							
E	10.11	10.51	0.398	0.414	3, 6							

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body (4) Dimension b1, b3 and c1 apply to base metal only

(5)

Controlling dimension: inches (6)

Thermal pad contour optional within dimensions E, H1, D2 and E1

 $^{(7)}\,$ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed

⁽⁸⁾ Outline conforms to JEDEC[®] TO-220, except D2, where JEDEC[®] minimum is 0.480"

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